NSN 5961-01-251-7838

Unitized Semiconductor Devices - Page 1 of 1



| View Online at https://aerobasegroup.com/nsn/5961-01-251-7838 |
|--|
| Inclosure Material: |
| Plastic |
| Overall Length: |
| Between 0.660 inches and 0.785 inches |
| End Application: |
| F-15 acft |
| Component Name And Quantity: |
| 4 transistor |
| Mounting Method: |
| Terminal |
| Semiconductor Material: |
| Silicon all transistor |
| Voltage Rating In Volts Per Characteristic: |
| 40.0 collector to emitter voltage/static/base open all transistor and 40.0 collector to base voltage/static/emitter open all transistor and 5. |
| emitter to base voltage, static, collector open all transistor |
| Current Rating Per Characteristic: |
| 1.00 amperes source cutoff current all transistor |
| Special Features: |
| All transistor junction pattern arrangement: pnp |
| Terminal Type And Quantity: |
| 14 pin |
| Shelf Life: |
| N/a |
| Unit Of Measure: |
| |
| Demilitarization: |
| No No |
| Fiig: |
| A110a0 |
| |